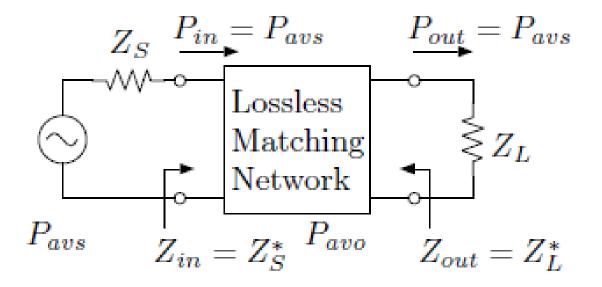
ECE 453 Wireless Communication Systems

Power Definitions

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Power Definitions



 P_{in} : Power delivered to input of 2-port

 P_{out} : Power delivered to the load

 P_{avs} : Power available from the source



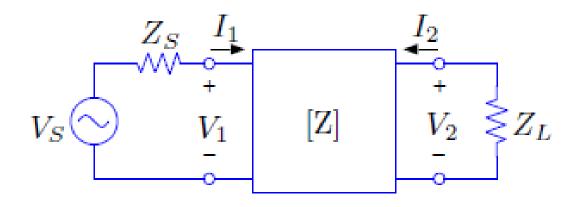
Power Gain Definitions

$$G = \frac{\text{Power delivered to load}}{\text{Power delivered to input of 2-port}} = \frac{P_{out}}{P_{in}}$$

$$G_T = \frac{\text{Power delivered to load}}{\text{Power available from source}} = \frac{P_{out}}{P_{avs}}$$

$$G_A = \frac{\text{Power available from output}}{\text{Power available from source}} = \frac{P_{avo}}{P_{avs}}$$

Power Available from a Source

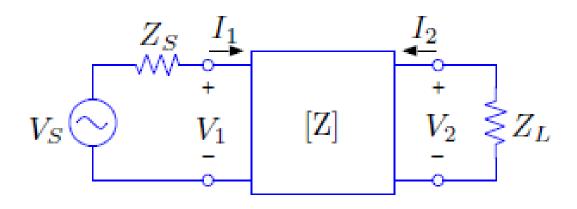


$$Z_S = R_S + jX_S$$

$$Z_L = R_L + jX_L$$

$$P_{avs} = \frac{\left|V_S\right|^2}{8R_S}$$

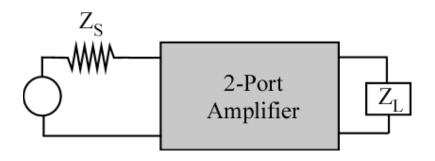
Transducer Gain with Z-Parameters



$$G_{T} = 4 \frac{\left| Z_{21} \right|^{2} R_{L} R_{S}}{\left| (Z_{11} + Z_{S})(Z_{22} + Z_{L}) - Z_{12} Z_{21} \right|^{2}}$$



The transducer power gain is defined as the power delivered to the load divided by the power available from the source.



$$\Gamma_{S} = \frac{Z_{S} - Z_{o}}{Z_{S} + Z_{o}} \qquad \qquad \Gamma_{L} = \frac{Z_{L} - Z_{o}}{Z_{L} + Z_{o}}$$

 Z_o is reference impedance for S parameters



Transducer Gain

Definition of transducer gain

$$G_T = \frac{P_{del}}{P_{avs}}$$

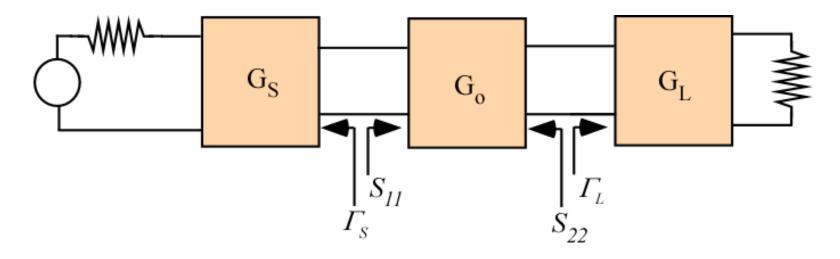
In terms of two-port scattering parameters

$$G_{T} = \frac{\left|S_{21}\right|^{2} \left(1 - \left|\Gamma_{S}\right|^{2}\right) \left(1 - \left|\Gamma_{L}\right|^{2}\right)}{\left|\left(1 - S_{11}\Gamma_{S}\right) \left(1 - S_{22}\Gamma_{L}\right) - S_{21}S_{12}\Gamma_{S}\Gamma_{L}\right|^{2}}$$

If we assume that the network is unilateral, then we can neglect S_{12} and get the unilateral transducer gain for S_{12} =0.

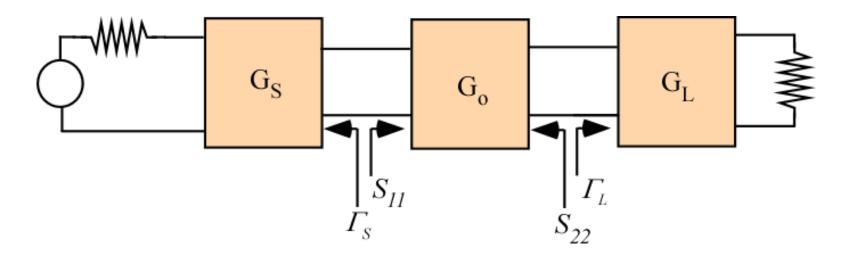
$$G_{TU} = \left| S_{21} \right|^{2} \frac{\left(1 - \left| \Gamma_{S} \right|^{2} \right)}{\left| 1 - S_{11} \Gamma_{S} \right|^{2}} \frac{\left(1 - \left| \Gamma_{L} \right|^{2} \right)}{\left| 1 - S_{22} \Gamma_{L} \right|^{2}}$$

The first term ($|S_{21}|^2$) depends on the transistor. The other 2 terms depend on the source and the load.



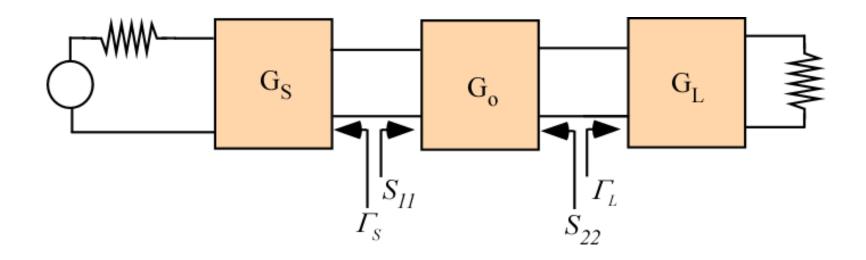
 G_s affects the degree of mismatch between the source and the input reflection coefficient of the two-port.





 G_L affects the degree of mismatch between the load and the output reflection coefficient of the 2-port.

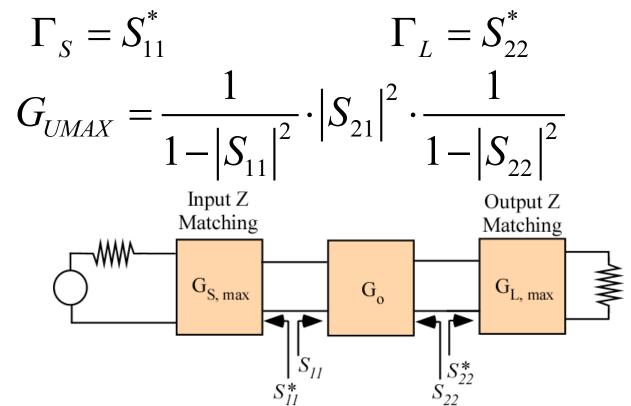


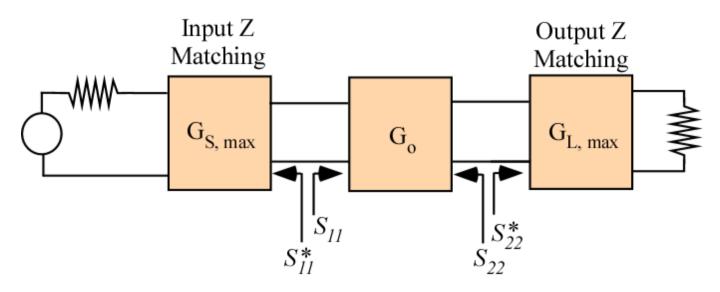


 G_o depends on the device and bias conditions



Maximum unilateral transducer gain can be accomplished by choosing impedance matching networks such that.





$$G_{UMAX}(dB) = G_{S \max}(dB) + G_o(dB) + G_{L \max}(dB)$$

For
$$\Gamma_S = S_{11}^*$$
, G_S is a maximum

For
$$|\Gamma_S| = 1$$
, G_S is 0



Dissipated Power

$$P_d = \frac{1}{2} \mathbf{a}^{\mathrm{T}} (\mathbf{U} - \mathbf{S}^{\mathrm{T}} \mathbf{S}^*) \mathbf{a}^*$$

The dissipation matrix D is given by:

$$\mathbf{D} = \mathbf{U} - \mathbf{S}^{\mathrm{T}} \mathbf{S}^{*}$$

Passivity insures that the system will always be stable provided that it is connected to another passive network

For passivity

- (1) the determinant of D must be ≥ 0
- (2) the determinant of the principal minors must be ≥ 0

Dissipated Power

When the dissipation matrix is 0, we have a lossless network**→**

$$\mathbf{S}^{\mathsf{T}}\mathbf{S}^{*}=\mathbf{U}$$

The S matrix is unitary.

For a lossless two-port:

$$\left|S_{11}\right|^2 + \left|S_{21}\right|^2 = 1$$

$$\left|S_{22}\right|^2 + \left|S_{12}\right|^2 = 1$$

If in addition the network is reciprocal, then

$$S_{12} = S_{21}$$
 and $|S_{11}| = |S_{22}| = \sqrt{1 - |S_{12}|^2}$

